# **Complementary NPN-PNP Silicon Power Bipolar Transistors**

The NJW3281G and NJW1302G are power transistors for high power audio, disk head positioners and other linear applications. **Features** 

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 5 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency
- These Devices are Pb–Free and are RoHS Compliant **Benefits**
- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwidth

#### Applications

- High-End Consumer Audio Products
  - Home Amplifiers
  - Home Receivers
- Professional Audio Amplifiers
  - Theater and Stadium Sound Systems
  - Public Address Systems (PAs)

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	250	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	250	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	V <sub>CEX</sub>	250	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	15	Adc
Collector Current – Peak (Note 1)	I <sub>CM</sub>	30	Adc
Base Current – Continuous	Ι <sub>Β</sub>	1.6	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate Above 25°C	P <sub>D</sub>	200 1.43	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.625	°C/W
Thermal Resistance, Junction-to-Ambient	R <sub>0JA</sub>	40	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

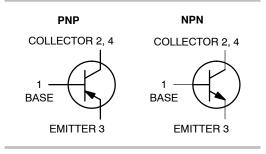
1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

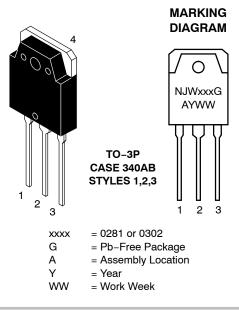


### **ON Semiconductor®**

http://onsemi.com

## 15 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS 200 WATTS





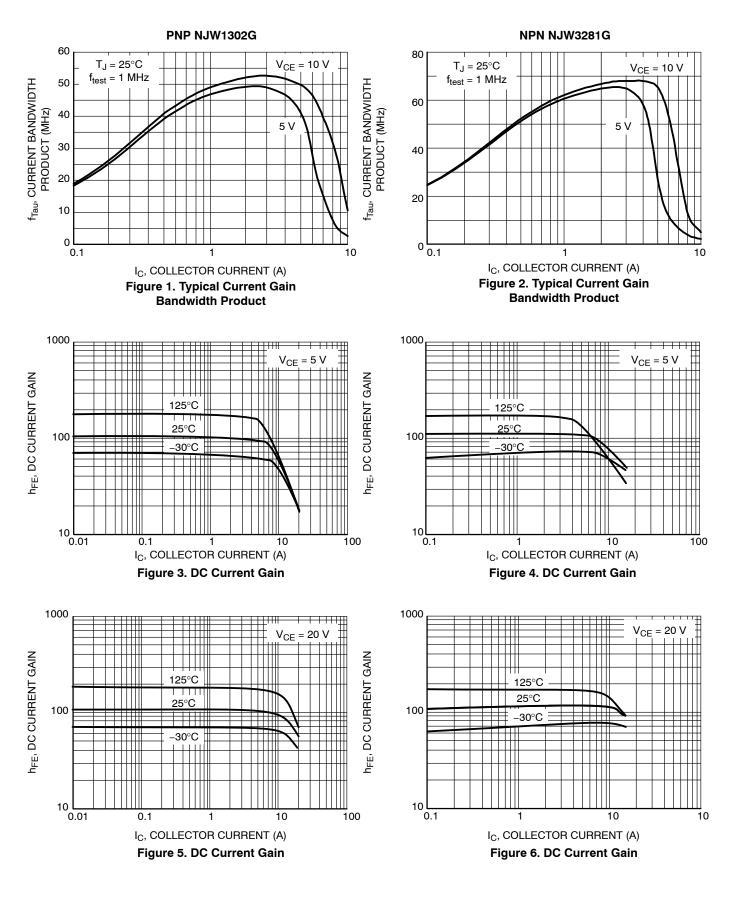
#### **ORDERING INFORMATION**

Device	Package	Shipping
NJW3281G	TO–3P (Pb–Free)	30 Units/Rail
NJW1302G	TO-3P (Pb-Free)	30 Units/Rail

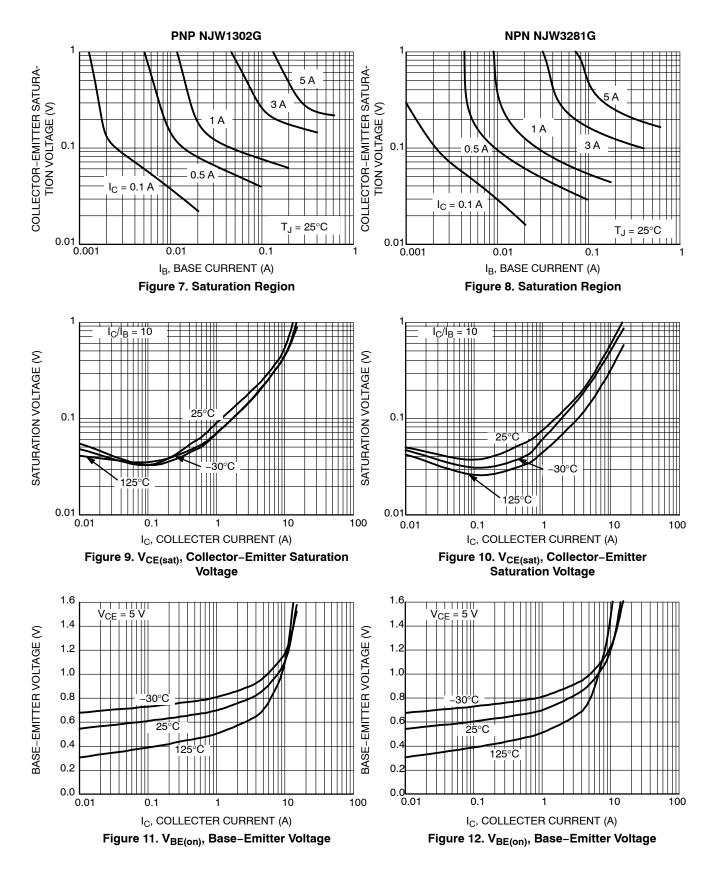
## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

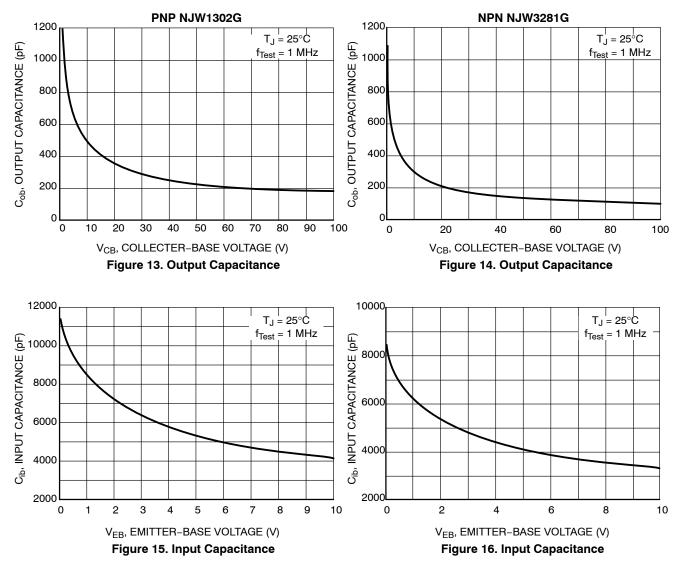
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	·				•
Collector-Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	V <sub>CEO(sus)</sub>	250	_	-	Vdc
Collector Cutoff Current $(V_{CB} = 250 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	_	-	50	μAdc
Emitter Cutoff Current ( $V_{EB} = 5 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	_	_	5	μAdc
SECOND BREAKDOWN	·				
Second Breakdown Collector with Base Forward Biased $(V_{CE} = 50 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$	I <sub>S/b</sub>	4	-	-	Adc
ON CHARACTERISTICS	·				
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 100 \text{ mAdc}, V_{CE} = 5 \text{ Vdc}) \\ (I_{C} = 1 \text{ Adc}, V_{CE} = 5 \text{ Vdc}) \\ (I_{C} = 3 \text{ Adc}, V_{CE} = 5 \text{ Vdc}) \\ (I_{C} = 5 \text{ Adc}, V_{CE} = 5 \text{ Vdc}) \\ (I_{C} = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc}) \\ (I_{C} = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc}) \end{array} $	h <sub>FE</sub>	75 75 75 60 45	- - - -	150 150 150 - -	_
Collector-Emitter Saturation Voltage $(I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc})$	V <sub>CE(sat)</sub>	_	0.4	0.6	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 8 Adc, V <sub>CE</sub> = 5 Vdc)	V <sub>BE(on)</sub>	_	_	1.5	Vdc
DYNAMIC CHARACTERISTICS	÷				
Current–Gain – Bandwidth Product ( $I_C = 1 \text{ Adc}, V_{CE} = 5 \text{ Vdc}, f_{test} = 1 \text{ MHz}$ )	f <sub>T</sub>	_	30	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f <sub>test</sub> = 1 MHz)	C <sub>ob</sub>	_	-	600	pF

### **TYPICAL CHARACTERISTICS**



### **TYPICAL CHARACTERISTICS**





#### **TYPICAL CHARACTERISTICS**

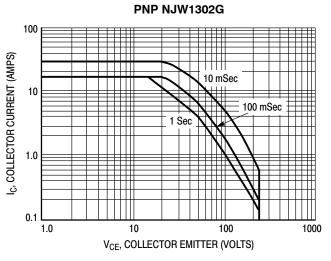


Figure 17. Active Region Safe Operating Area

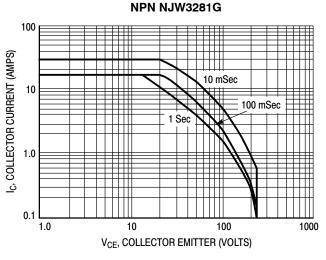


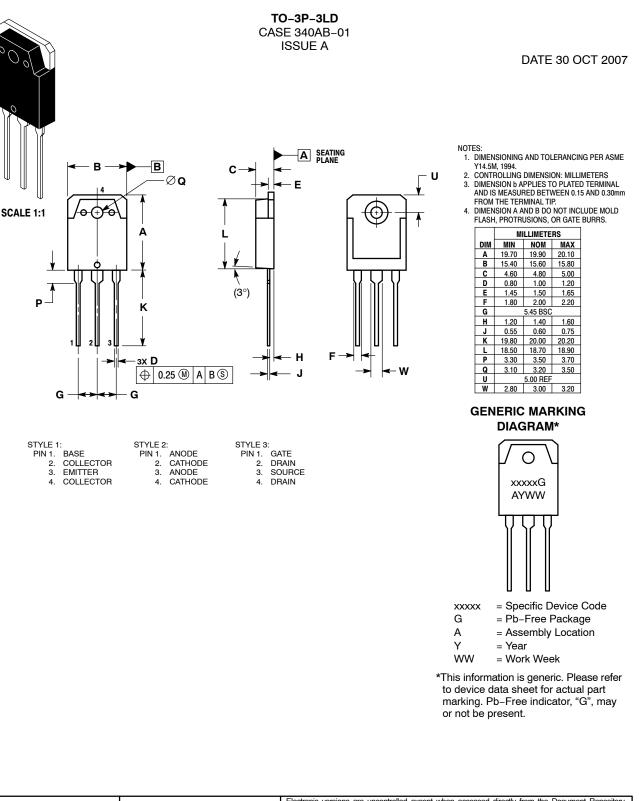
Figure 18. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 17 and 18 is based on  $T_{J(pk)} = 150^{\circ}C$ ;  $T_C$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





DOCUMENT NUMBER:	98AON25095D Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	TO-3P-3LD		PAGE 1 OF 1		
ON Semiconductor and (1) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the					

© Semiconductor Components Industries, LLC, 2019

rights of others.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative